#### MECHANISM FOR SUPPRESSION OF RADIATION-INDUCED SEGREGATION BY OVERSIZED SOLUTE ADDITION IN AUSTENITIC STAINLESS STEEL

by

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To my family

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## TABLE OF CONTENTS

DEDICA	TION	ii
ACKNO	WLEDGEMENTS	iii
LIST OF	FIGURES	ix
LIST OF	TABLES	xxiv
LIST OF	APPENDICES	xxviii
СНАРТЕ	ER	
1.	INTRODUCTION	1
2.	BACKGROUND  2.1 Radiation-Induced Segregation  2.1.1 Cause of RIS  2.1.2 RIS Sensitivity  2.1.3 Experiments in RIS  2.1.4 Effect of Irradiation Particle Type on RIS  2.1.5 Effects of Dislocation Loops on RIS  2.1.6 Effects of Void Swelling on RIS  2.1.7 Effects of Grain Boundary Orientation on RIS  2.2 Mechanisms of RIS  2.2.1 Early Work in RIS Mechanisms  2.2.2 RIS Mechanisms for Binary Alloy System  2.2.3 RIS Mechanisms for a Ternary Alloy System  2.3 Experimental Results in Oversized Solute Additions on RIS  2.3.2 Effects of Oversized Solute Additions on RIS  2.4.1 Linear Size Factors for Oversized Solutes  2.4.2 Solute-Defect Binding  2.4.3 Interstitial Impurity Trapping	5
3.	OBJECTIVE	97

4.	EXPERIMENTAL PROCEDURES	99
	4.1. Alloys and Sample Preparation	99
	4.1.1 Alloys	
	4.1.2. Alloy Processing	
	4.1.3. Preparation	
	4.2. Sample Irradiation	102
	4.2.1 Overview of Irradiation Setup	102
	4.2.2 Determining Displacement Damage	
	4.2.3 Calculating Radiation Dose	
	4.2.4 Aperture System and Beam Scanning	106
	4.2.5 Thermocouples	108
	4.2.6 Irradiation Monitoring	
	4.2.7 Radioactivity and Beta Counting	
	4.3 Post-Irradiation Sample Preparation	
	4.3.1 TEM Preparation.	
	4.3.2 Ion Milling	
	4.4 Radiation-Induced Segregation	
	4.4.1 STEM Instrumentation.	
	4.4.2 STEM/EDS Measurements of RIS	115
	4.4.3 STEM/EDS Composition Calculation	116
	4.5 Dislocation Loop Imaging	
	4.5.1 Dark-field Technique	
	4.5.3 Loop Measurements	
	4.6 Determination of Oversized Solute in Solution	
	4.6.1 X-ray Diffraction	119
	4.6.2 SEM Imaging	120
	4.6.3 TEM Imaging	121
	4.6.4 FIB and LEAP.	121
	4.7 Error analysis	123
5.	EXPERIMENTAL RESULTS	150
	5.1 Radiation-Induced Segregation Results	151
	5.1.1 Grain Boundary Segregation	
	5.1.2 RIS in the +Zr Alloys at 400°C	
	5.1.3 RIS in the +Hf Alloys at 400°C	
	5.1.4 RIS in the +Zr Alloys at 500°C	157
	5.1.5 RIS in the +Hf Alloys at 500°C	158
	5.2 Results from Dislocation Loop Imaging	
	5.2.1 Dislocation Loops for the +Zr Alloys	
	5.2.2 Dislocation Loops for the +Hf Alloys	161
	5.3 Determination of the Amount of Oversized Solute in Solution	162
	5.3.1 X-ray Diffraction	164
	5.3.2 SEM Imaging of Carbides	165
	5.3.3 TEM Imaging Analysis	
	5.3.4 LEAP Analysis	

6.	MODELING OF OVERSIZED SOLUTE EFFECTS ON RIS	235
	6.1 RIS Modeling	
	6.1.1 The MIK Model	235
	6.1.2 The MIK Model with Trapping	236
	6.1.3 Model Results	
	6.1.4 Model Benchmarking	239
	6.1.5 MIK Model Results	
	6.1.5.1 Temperature Dependence	240
	6.1.5.2 Dose Dependence	241
	6.1.5.3 Dose Rate Dependence	
	6.1.6 MIK-T Model	
	6.1.6.1 Binding Energy	242
	6.1.6.2 Trapping Radius	243
	6.1.6.3 Recombination Radius	
	6.1.7 Variation of Experimental Parameters	245
	6.1.7.1 Temperature	
	6.1.7.2 Dose	
	6.1.7.3 Dose Rate	248
	6.1.7.4 Oversized Solute Concentration	249
	6.1.8 Sensitivity Analysis	249
	6.2 Determination of Binding Energies	
	6.2.1 Ab initio Method	252
	6.2.2 Binding Energy Determination	253
	6.2.3 Differences between Zr and Hf	255
	6.2.4 Trapping and Recombination Radii	255
	6.2.5 Lattice Parameters	256
	6.3 Model Results for the Alloys	257
	6.3.1 MIK-T Model Results	257
	6.3.2 Alloy Results	258
7.	DISCUSSION	294
	7.1 Validity of RIS Results	294
	7.1.1 Comparison of Reference Alloy RIS to Literature Values	295
	7.1.2 MIK Model Compared to Reference Alloy RIS	
	7.1.3 Comparison of Reference Alloy Loop Microstructure with Literature Values	301
	7.1.4 Relationship between Loop Microstructure and RIS	
	7.1.5 Effect of Proton Energy on RIS	
	7.2 Comparison of MIK-T Model Results with Experimental RIS	507
	1	308
	7.3 Mechanism Responsible for Loss of Effect from Oversized Solutes	
	7.3.1 Loss of Oversized Solute Effectiveness due to Solute	
	Poisoning	311
	7.3.2 Loss of Oversized Solute to Precipitation	
	7.3.3 Atom Prohe Analysis	321

8. CONCLUSIONS	354
Future Work	355
APPENDICES	358
BIBLIOGRAPHY	480

## LIST OF FIGURES

## <u>Figure</u>

2.1	(a) The diffusion of A atoms through the vacancy flux is greater than the diffusion of B atoms through the vacancy flux; (b) the diffusion of B atoms through the interstitial flux is greater than A atoms; and (c) the resulting concentration profile shows the enrichment of B atoms and depletion of A atoms at the grain boundary.	57
2.2	Calculated steady-state concentration profiles of element A in a B-25%A alloy as a function of distance from the grain boundary. The dose rate is 10 <sup>-3</sup> dpa/s	58
2.3	The temperature and dose rate regime in which stainless steels are susceptible to RIS	59
2.4	Experimental Cr GB measurements after neutron irradiation for 300 series stainless steels at various temperatures	60
2.5	Concentration profiles of 304SS irradiated with neutrons at 288°C for a commercial purity alloy, showing (a) Fe, Cr and Ni, and (b) Si, P and S grain boundary concentrations; a high purity alloy, showing the grain boundary concentration for (c) Fe, Cr and Ni, and (d) Si and P	61
2.6	Change in grain boundary Ni and Cr concentrations for a series of HP 304SS with additions of Si or Mo after proton irradiation at 360°C to a dose of 5.5 dpa	62
2.7	Amount of Cr depletion at the grain boundary as a function of radiation dose for a variety of Fe-based, 304 and 316 stainless steels. Symbol shading represents the particle type, with grey, closed symbols for proton irradiations, open symbols for electron irradiations, and x symbols for He <sup>+</sup> irradiations.	63
2.8	Grain boundary segregation for Ni, Cr and Fe as a function of Ni concentration for a constant 15Cr alloy after electron irradiation at 500°C to 7 dpa	64

2.9	Grain boundary segregation for Ni, Cr and Fe as a function of Cr concentration for a constant 20Ni alloy after electron irradiation at 500°C to	65
2.10	7 dpa Ni and Cr grain boundary concentration as a function of dose after proton irradiation of a Fe-20Cr-24Ni alloy at 400°C	
2.11	Ni and Cr grain boundary concentration as a function of temperature after proton irradiation of a Fe-20Cr-24Ni alloy to a dose of 0.5 dpa.	67
2.12	Network, loop and total dislocation density as a function of dose.	68
2.13	The formation and loss of DLFZ near a grain boundary as a function of dose	69
2.14	Dose dependence of the DLFZ width under 1 MeV electron irradiation at 523 K	70
2.15	Width of RIS profile relative to the width of the DLFZ under 1 MeV electron irradiation at 1 dpa. The calculated solid line is not convoluted to match the experimental measurements.	71
2.16	The tilt angle between two grain boundaries has a strong effect on the resulting RIS profile, with increasing tilt angle corresponding to increasing RIS. Depletion is small for (a) a small tilt angle of 3.5° and (b) a large tilt angle of 60°.	72
2.17	RIS dependence on misorientation tilt angle after electron irradiation at 350°C.	73
2.18	Concentrations of point defects and defect-solute complexes at the center of a thin foil irradiated at 0°C as a function of irradiation time.	74
2.19	Concentrations of point defects and defect-solute complexes at the center of a thin foil irradiated at 500°C as a function of irradiation time	75
2.20	Representation of the migration energy, defined as the different between the equilibrium energy and the saddle point energy.	76
2.21	Comparing experimental Cr concentration levels from proton-irradiated stainless steels to calculated concentrations from the MIK model.	77
2.22	Cr concentration at the grain boundary as a function of temperature for proton-irradiated Fe-20Cr-24Ni after 0.5 dpa. The symbols represent AES measurements, the upper line is the MIK model calculated Cr concentration, while the lower line is calculated by the Perks model	78

2.23	Cr concentrations at the grain boundary as a function of dose for proton-irradiated Fe-20Cr-24Ni at 400°C. The symbols represent AES measurements, the upper line is the MIK model calculated Cr concentration, while the lower line is calculated by the Perks model.	79
2.24	Grain boundary Cr depletion as a function of dose for a variety of 304 and 316 stainless steel alloys. The oversized solute additions include Zr, Hf, Ti, and Nb. Symbol shading represents the particle type, with grey, closed symbols for proton irradiations, black, closed symbols for neutron irradiations, cross-hatch symbols for He <sup>+</sup> irradiations, and open symbols for electron irradiations. Meanwhile, symbol shape represents the oversized solute type, with square symbols for Zr, diamonds for Hf, triangles for Ti and circles for Nb.	80
2.25	Chromium grain boundary concentration profiles for various oversized solute alloys after 1 MeV electron irradiation to 10.8 dpa at 500°C. Not all oversized solute additions resulted in a decrease in Cr depletion	81
2.26	Grain boundary segregation as a function of Nb concentration after electron irradiation to 7.2 dpa at 773 K in Fe-16Cr-13Ni.	82
2.27	Grain boundary segregation versus linear size factor and vacancy-solute binding energy for solute additions of 0.5 at% of Ti, Nb, Zr, and Hf in Fe-18Cr-12Ni after electron irradiation to 10.8 dpa at 723 K	83
2.28	Cr concentration profile as a function of distance from the grain boundary for 316L and 316+0.2%Zr alloys after irradiation with 1 MeV electrons to a dose of 10 dpa at 450°C.	84
2.29	Focusing on Cr, the grain boundary depletion as a function of temperature for 316L and 316+0.2%Zr after 1 MeV electron irradiation.	85
2.30	Cr concentration as a function of the Zr alloy concentration after 400 keV He <sup>+</sup> irradiation at 500°C. The closed symbols represent a dose of 0.85 dpa and the open symbols are for 3.4 dpa.	86
2.31	The change in grain boundary Cr concentration for a reference Fe-18Cr-8Ni, 1.25Mn irradiated with protons at 400°C to a dose of 0.5 dpa, compared to two similar oversized solute alloys with 0.04 and 0.16at% Zr irradiated to 1.0 dpa.	87
2.32	The vacancy-cluster density of Fe-16Cr-17Ni alloys with Nb and Ti additions after 1 MeV electron irradiation to 0.1 dpa.	88
2.33	Void swelling as a function of temperature after 1 MeV electron irradiation to 2.0 dpa for Fe-16Cr-17Ni alloys with Nb and Ti additions	89

2.34	Arrhenius plot of the interstitial loop density in Fe-16Cr-17Ni with additions of Nb or Ti.	90
2.35	Void swelling as a function of dose for Hf and Pt-modified 316SS after Ni <sup>++</sup> irradiation at 500°C	91
2.36	Loop volume fraction as a function of dose for Hf and Pt-modified 316SS after Ni <sup>++</sup> irradiation at 500°C.	92
2.37	Loop diameter as a function of dose for Hf and Pt-modified 316SS after Ni <sup>++</sup> irradiation at 500°C.	93
2.38	Fine-scale precipitate formation of ZrC and HfC after fast neutron irradiation to 35 dpa at 600°C.	94
2.39	The fraction of occupied solute-defect traps as a function of the binding energy for defect trapping. Fractions are shown for 650°C at 10 <sup>-3</sup> dpa/s and 500°C at 10 <sup>-6</sup> dpa/s	95
2.40	Amount of segregation for Ni and Cr as a function of binding energy for irradiation at 573K and 773K for a Fe-15Cr-20Ni alloy.	96
4.1	TEM sample bar design produced by electron-discharge machining for proton irradiation.	128
4.2	(a) Position of the Stinger thermal imager in capturing infrared radiation from the samples during irradiation, and (b) illustration of the sample stage that was used for proton irradiation of the TEM bars	129
4.3	Photograph of eight samples plus two guide bars mounted on the stage prior to irradiation. The image shows thermocouples spot-welded onto the samples.	130
4.4	A drawing of the hold-down bars used to secure samples on the stage during irradiation.	131
4.5	View of the copper stage with samples mounted, thermocouple wires, and hold-down bars	132
4.6	A view of the damage rate as a function of depth into the irradiated surface as calculated by SRIM 2006 for 3.2 MeV protons in Fe-16Cr-13Ni alloy. A relatively uniform damage region is created from a depth of 5 – 35 $\mu$ m, with a maximum damage depth at $\sim$ 43 $\mu$ m.	133

4.7	A closer view of the displacement rate as a function of damage layer depth as calculated by SRIM 2006. An average displacement rate is taken at $\sim 26$ $\mu m$ for 3.2 MeV $p^+$ , where the displacement rate is $5.3 \times 10^{-5}$ displacements/Å/ion, and at $\sim 12$ $\mu m$ for 2.0 MeV $p^+$ , where the displacement rate is $8.0 \times 10^{-5}$ displacements/Å/ion	134
4.8	Setup of the laser alignment procedure for proper alignment of the aperture system on the irradiation stage	135
4.9	Representation of the laser beam pattern hitting the samples with a properly aligned stage	136
4.10	Schematic of the tantalum aperture system used to measure aperture current and shape the beam pattern for sample irradiation.	137
4.11	Schematic of beam-on-aperture overlap, with the resulting stage-to-aperture current ratio using a 3-mm beam size.	138
4.12	Beam scanning pattern of the raster scanner used during proton irradiation,	139
4.13	Beam profile monitor, including the beam selector knob set at 'beam profile' for beam size measurements.	140
4.14	Image of the oscilloscope showing the positions of the fiduciary marks	141
4.15	Oscilloscope image showing BPM current signal for beam size measurements.	142
4.16	Stinger pyrometer temperature history for an irradiation, showing the number of measured temperature data points for all samples on the irradiation stage.	143
4.17	Beta activity model for predicting the number of beta counts as a function of time expected for an irradiation using 3.2 MeV p <sup>+</sup> of austenitic stainless steels. The combination of both exponential equations provided in the figure is used to predict the number of beta counts.	144
4.18	Illustration of TEM discs cut from an irradiated TEM bar.	
	Sample foil with grain boundary aligned edge-on and the excitation volume of the electron beam as it passes through the specimen	
4.20	STEM image of a properly aligned grain boundary, with the boundary defined as a high-contrast line, including beam damage from STEM/EDS RIS measurements across the boundary.	147

4.21	Refrod streaks, in (a) and (b), representing faulted dislocation loops, appear between the 111 and 200 spots along the g = 113 reflection for the [0 1 1] zone axis.	148
4.22	ZrC precipitate phase in 316+HiZr, imaged using a BSE detector in SEM	149
5.1	Concentration profile as a function of distance from the grain boundary for Fe, Cr and Ni for the Ref-Zr alloy irradiated at 400°C to 3 dpa. The left y-axis is for Fe concentration while Cr and Ni concentrations are plotted on the right y-axis.	196
5.2	Cr concentration profiles as a function of distance from the grain boundary at 400°C for Ref-Zr, LoZr and HiZr, at doses of (a) 3 dpa, (b) 7 dpa, and (c) 10 dpa.	197
5.3	Change in grain boundary Ni and Cr concentration for the +Zr alloy series after proton irradiation at 400°C to doses of 3, 7 and 10 dpa.	198
5.4	Cr concentration profiles as a function of distance from the grain boundary at 400°C for Ref-Hf, LoHf and HiHf, at doses of (a) 3 dpa, (b) 7 dpa, and (c) 10 dpa.	199
5.5	Change in grain boundary Ni and Cr concentration for the +Hf alloy series after proton irradiation at 400°C to doses of 3, 7 and 10 dpa	200
5.6	Cr concentration profiles as a function of distance from the grain boundary at 500°C for Ref-Zr, LoZr and HiZr, at doses of (a) 1 dpa and (b) 3 dpa	201
5.7	Change in grain boundary Ni and Cr concentration for the +Hf alloy series after proton irradiation at 500°C to doses of 1 and 3 dpa	202
5.8	Cr concentration profiles as a function of distance from the grain boundary at 500°C for Ref-Hf, LoHf and HiHf, at doses of (a) 1 dpa and (b) 3 dpa	203
5.9	Change in grain boundary Ni and Cr concentration for the +Hf alloy series after proton irradiation at 500°C to doses of 1 and 3 dpa.	204
5.10	Dislocation loop images at 400°C, 3 dpa of (a) Ref-Zr, (b) LoZr, and (c) HiZr	205
5.11	Dislocation loop images at 400°C, 7 dpa of (a) Ref-Zr, (b) LoZr, and (c) HiZr	206
5.12	Dislocation loop size distributions of the relative frequency of loop diameter for the +Zr alloys after 400°C irradiation to 3 dpa for (a) Ref-Zr, (b) LoZr,	

	and (c) HiZr, and to 7 dpa for (d) Ref-Zr, (e) LoZr, and (f) HiZr. Vertical lines denote the average loop diameter.	207
5.13	Average dislocation loop diameter for the +Zr alloys as a function of dose from 3 – 7 dpa after proton irradiation at 400°C.	208
5.14	Average dislocation loop density for the +Zr alloys as a function of dose from 3 – 7 dpa after proton irradiation at 400°C.	209
5.15	Total loop line length for the +Zr alloys as a function of dose from 3 – 7 dpa after 400°C proton irradiation.	210
5.16	Dislocation loop images at 400°C, 3 dpa of (a) Ref-Hf, (b) LoHf, and (c) HiHf	211
5.17	Dislocation loop images at 400°C, 7 dpa of (a) Ref-Hf, (b) LoHf, and (c) HiHf	212
5.18	Dislocation loop size distributions of the relative frequency of loop diameter for the +Zr alloys after 400°C irradiation to 3 dpa for (a) Ref-Hf, (b) LoHf, and (c) HiHf, and to 7 dpa for (d) Ref-Hf, (e) LoHf, and (f) HiHf. Vertical lines denote the average loop diameter.	213
5.19	Average dislocation loop diameter for the +Hf alloys as a function of dose from 3 – 7 dpa after proton irradiation at 400°C.	214
5.20	Average dislocation loop density for the +Hf alloys as a function of dose from 3 – 7 dpa after proton irradiation at 400°C.	215
5.21	Total loop line length for the +Hf alloys as a function of dose from 3 – 7 dpa after 400°C proton irradiation.	216
5.22	XRD pattern for Ref-Zr showing intensity as a function of $2\theta$ , scanned from $2\theta = 20 - 70^{\circ}$ . The peaks for austenite are highlighted by arrows.	217
5.23	XRD pattern for LoZr showing intensity as a function of $2\theta$ , scanned from $2\theta = 20 - 70^{\circ}$ . The peaks for austenite are highlighted by arrows. The gray lines represent the most strongly diffracting (highest intensity) $2\theta$ angles for ZrC in this $2\theta$ range and include the (hkl) planes for each line	218
5.24	XRD pattern for HiZr showing intensity as a function of $2\theta$ , scanned from $2\theta = 20 - 70^{\circ}$ . The peaks for austenite are highlighted by arrows. The gray lines represent the most strongly diffracting (highest intensity) $2\theta$ angles for ZrC in this $2\theta$ range and include the (hkl) planes for each line	219

5.25	XRD pattern for Ref-Zr showing intensity as a function of $2\theta$ , scanned from $2\theta = 20 - 70^{\circ}$ . The peaks for austenite are highlighted by arrows	220
5.26	XRD pattern for LoHf showing intensity as a function of $2\theta$ , scanned from $2\theta = 20 - 70^{\circ}$ . The peaks for austenite are highlighted by arrows. The gray lines represent the most strongly diffracting (highest intensity) $2\theta$ angles for HfC in this $2\theta$ range and include the (hkl) planes for each line. Note that these lines do not correspond to any diffraction peaks, meaning that no HfC was identified.	221
5.27	XRD pattern for HiHf showing intensity as a function of $2\theta$ , scanned from $2\theta = 20 - 70^{\circ}$ . The peaks for austenite are highlighted by arrows. The gray lines represent the most strongly diffracting (highest intensity) $2\theta$ angles for HfC in this $2\theta$ range and include the (hkl) planes for each line	222
5.28	SEM-BSE images showing high-contrast precipitates for (a) LoZr, (b) HiZr, (c) LoHf, and (d) HiHf alloys. These precipitates are highlighted in (a) for LoZr.	223
5.29	TEM image of the HfC precipitate microstructure in HiHf in the unirradiated condition.	224
5.30	TEM image of the ZrC precipitate microstructure in HiZr in the unirradiated condition.	225
5.31	Size distribution of HfC precipitates in unirradiated HiHf	226
5.32	Size distribution of ZrC precipitates in unirradiated HiZr.	227
5.33	Mass/charge ratio for LoZr: (a), (b), and (c) in the unirradiated condition, (d) at 3 dpa, and (e) at 7 dpa. Zr intensity peaks are shown with Mo peaks to demonstrate the presence of the 2+ Zr <sup>90</sup> peak and the overlap of subsequent 2+ Zr peaks with Mo 2+ peaks. The presence of Zr is detected for the unirradiated condition in (b).	228
5.34	Mass/charge ratio for HiZr: (a) in the unirradiated condition, (b) and (c) at 3 dpa, and (d) at 7 dpa. Zr intensity peaks are shown with Mo peaks to demonstrate the presence of the 2+ Zr <sup>90</sup> peak and the overlap of subsequent 2+ Zr peaks with Mo 2+ peaks. The presence of Zr is detected in the unirradiated condition and at 3 and 7 dpa, shown in (b), (c) and (d). Unidentified peaks occur (b), (c) and (d) which cannot be attributed to any particular element.	229
5.35	Mass/charge ratio for (a) unirradiated LoHf, (b) unirradiated HiHf, and (c) HiHf at 3 dpa. Hf intensity peaks are shown for the HiHf alloy only. The absence of Hf peaks for LoHf indicates that the Hf in solution is below the	

	detectable limit. The presence of Hf is detected in the unirradiated condition in (b) but uncertain in (c), due to additional peaks with a lower mass/charge ratio than Hf which cannot be identified. Notice that any Hf in solution in LoHf is below the detection limit and cannot be seen in the mass/charge ratio spectrum.	230
5.36	The final image taken in FIB prior to last annular milling process. Although the image is blurry and ma require additional focusing, more scans for the purpose of focusing mean more Ga <sup>+</sup> ion implantation into the sample tip	231
5.37	Atom maps of Ni for (a) unirradiated HiZr, (b) LoZr at 3 dpa, and (c) HiZr at 7 dpa. No precipitation of Ni is observed until after irradiation of the alloys.	232
5.38	Atom maps of Si for (a) unirradiated HiZr, (b) LoZr at 3 dpa, and (c) HiZr at 7 dpa. No clustering of Si is observed until after irradiation of the alloys	233
5.39	Atom maps of oversized solute for (a) unirradiated LoZr (b) HiZr at 7 dpa, and (c) unirradiated HiHf. The distribution of oversized solute does not appear to be clustered nor is there any change in distribution due to irradiation dose.	234
6.1	Benchmarking of the MIK model, showing grain boundary Cr concentration as a function of temperature for Fe-20Cr-24Ni alloy with a dose rate of $7x10^{-6}$ dpa/s at 0.5 dpa with MIK in black and MIK-T in green.	267
6.2	Benchmarking of the MIK model, showing grain boundary Ni concentration as a function of temperature for Fe-20Cr-24Ni alloy with a dose rate of $7x10^{-6}$ dpa/s at 0.5 dpa with MIK in black and MIK-T in orange	268
6.3	Variation of grain boundary Ni and Cr concentration as a function of temperature from 200 – 600°C for the MIK model at 1 dpa	269
6.4	Grain boundary concentrations for Ni and Cr as a function of dose for the MIK model at 400°C	270
6.5	Variation of grain boundary Ni and Cr concentration as a function of dose rate from $10^{-8} - 10^{-3}$ dpa/s for the MIK model	271
6.6	Grain boundary concentrations for Cr and Ni as a function of the binding energy from 0 to 1.0 eV at 400°C, 1 dpa, with a dose rate of 10 <sup>-6</sup> dpa/s and a solute concentration of 0.5 at%. The reference value for studying the variation of other MIK-T model input parameters is shown in the figure by a vertical line at 0.5 eV	272

6.7	Grain boundary concentrations for Cr and Ni as a function of the oversized solute trapping radius from 0 – 1 nm at 400°C, 1 dpa, with a dose rate of 10 <sup>-6</sup> dpa/s, a binding energy of 0.5 eV, recombination radius of 0.5 nm, and solute concentration of 0.5 at%. The reference value for studying the variation of other MIK-T model input parameters is shown in the figure by a vertical line at 0.5 nm. The shaded region represents a radius less than the 1 <sup>st</sup> nearest neighbor distance of 0.3 nm.	273
6.8	Grain boundary concentrations for Cr and Ni as a function of the solute-vacancy recombination radius from $0-1$ nm at $400^{\circ}$ C, 1 dpa, with a dose rate of $10^{-6}$ dpa/s, a binding energy of $0.5$ eV, trapping radius of $0.5$ nm, and solute concentration of $0.5$ at%. The reference value for studying the variation of other MIK-T model input parameters is shown in the figure by a vertical line at $0.5$ nm. The shaded region represents a radius less than the $1^{st}$ nearest neighbor distance of $0.3$ nm.	274
6.9	Grain boundary Cr concentrations as a function of temperature at 10 <sup>-6</sup> dpa/s and 1 dpa for the MIK and MIK-T models, with a binding energy of 1.0 eV and solute concentration of 0.5 at% for the MIK-T model.	275
6.10	Percent difference in the grain boundary Cr concentration between the MIK and MIK-T models as a function of temperature at 10 <sup>-6</sup> dpa/s and 1 dpa	276
6.11	Value of the exponential in the solute-vacancy dissociation rate as a function of temperature with a binding energy of 1.0 Ev	277
6.12	The release and recombination rates divided by the trapping rate as a function of temperature, at 10 <sup>-6</sup> dpa/s, 1 dpa.	278
6.13	The recombination rate relative to its maximum value, at 200°C, as a function of temperature, at 10 <sup>-6</sup> dpa/s, 1 dpa.	279
6.14	Grain boundary Cr concentrations as a function of dose for the MIK and MIK-T models at 400°C	280
6.15	Percent difference in the grain boundary Cr concentration between the MIK and MIK-T models as a function of dose at 10 <sup>-6</sup> dpa/s and 400°C	281
6.16	Grain boundary Cr concentrations as a function of dose rate at 400°C and 1 dpa	282
6.17	The trapped vacancy concentration as a function of dose rate on the left y-axis in blue, and the trapped vacancy concentration divided by the defect production rate as a function of dose on the right y-axis in red, at 400°C and 1 dpa	283

6.18	Concentrations for the freely migrating vacancies and the trapped vacancies as a function of dose rate at 400°C, 1 dpa.	284
6.19	Grain boundary concentrations for Cr and Ni as a function of the oversized solute concentration from 0 to 1.0 at% at 400°C and 1 dpa, with a binding energy of 0.5 eV and trapping and recombination radii of 0.5 nm. The reference value for studying the variation of other MIK-T model input parameters is shown in the figure by a vertical line at 0.5 at%.	285
6.20	Binding energy as a function of nearest neighbor distance from the oversized solute assuming a non-spin-polarized (non-magnetic) system. The top x-axis also includes the distance from the origin, in nm.	286
6.21	Relaxation of Hf and Zr ions with 1 <sup>st</sup> nn vacancies. The vacancy lattice position is by the tip of the horizontal arrows. Relaxation of Zr ion toward the vacancy position is much greater than the relaxation of Hf, accounting for the larger binding energy for Zr compared to Hf.	287
6.22	The nn positions relative to the oversized solute (OS) atom at the origin for a fcc cell. The 1 <sup>st</sup> , 2 <sup>nd</sup> , 3 <sup>rd</sup> , 4 <sup>th</sup> , and 6 <sup>th</sup> nn positions are shown. The 5 <sup>th</sup> nn position rests in the face of the adjacent cell away from the oversized solute, one lattice parameter distance from the 1 <sup>st</sup> nn position.	288
6.23	Effect of binding energy on the value of the exponential in the solute-vacancy dissociation rate	289
6.24	Calculated change in grain boundary concentrations for the +Zr alloys at doses of 3, 7 and 10 dpa at 400°C with a solute-vacancy binding energy of 1.08 eV	290
6.25	Calculated change in grain boundary concentrations for the +Hf alloys at doses of 3, 7 and 10 dpa at 400°C with a solute-vacancy binding energy of 0.71 eV	291
6.26	Calculated change in grain boundary concentrations for the +Zr alloys at doses of 1 and 3 dpa at 500°C with a solute-vacancy binding energy of 1.08 eV	292
6.27	Calculated change in grain boundary concentrations for the +Hf alloys at doses of 1 and 3 dpa at 500°C with a solute-vacancy binding energy of 0.71 eV	293
7.1	A comparison of Cr depletion between the reference alloys in this study and literature values for proton irradiation data, showing the amount of grain boundary (GB) Cr depletion as a function of dose for austenitic stainless steels at temperatures of 360 – 500°C	324

1.2	literature values for neutron irradiation data (black symbols) and proton irradiation data (grey symbols), showing the amount of grain boundary (GB) Cr depletion as a function of dose for austenitic stainless steels at temperatures of 275 – 500°C	325
7.3	A comparison of Ni enrichment between the reference alloys in this study and literature values for proton irradiation data, showing the amount of grain boundary (GB) Ni enrichment as a function of dose for austenitic stainless steels at temperatures of $360-500^{\circ}\mathrm{C}$	326
7.4	A comparison at 400°C of the MIK model and experimental measurements for the change in grain boundary Ni and Cr concentrations for Ref-Zr and Ref-Hf.	327
7.5	A comparison at 500°C of the MIK model and experimental measurements for the change in grain boundary Ni and Cr concentrations for Ref-Zr and Ref-Hf.	328
7.6	Average loop diameters for the reference alloys in this study compared to literature values for 316-type stainless steels irradiated with protons at temperatures of 360°C and 400°C	329
7.7	Average loop diameters for the reference alloys in this study compared to literature values for 316-type stainless steels irradiated with protons (grey symbols) and neutrons (black symbols) at temperatures of 275 – 400°C	330
7.8	Average loop densities for the reference alloys in this study compared to literature values for 316-type stainless steels irradiated with protons at temperatures of 360°C and 400°C.	331
7.9	Average loop densities for the reference alloys in this study compared to literature values for 316-type stainless steels irradiated with protons (grey symbols) and neutrons (black symbols) at temperatures of 275 – 400°C	332
7.10	Average loop diameters for all alloys in this study, plotted vs. dose for 3 and 7 dpa at 400°C	333
7.11	Average loop densities for all alloys in this study, plotted vs. dose for 3 and 7 dpa at 400°C	334
7.12	Loop line length as a function of grain boundary Cr depletion for the +Zr alloys at 3 and 7 dpa. 400°C.	335

7.13	Loop line length as a function of grain boundary Cr depletion for the +Hf alloys at 3 and 7 dpa, 400°C.	336
7.14	Measured changes in grain boundary Ni and Cr concentrations for the alloys HiZr, Ref-Hf, and HiHf at doses of 3 and 7 dpa, using either 2 MeV or 3.2 MeV protons. The comparison of Cr depletion between 2 MeV and 3.2 MeV irradiations shows that grain boundary segregation values are not affected by protons in this energy range.	337
7.15	Change in grain boundary Cr and Ni concentration at 400°C to doses of 3, 7 and 10 dpa for all measurements for the +Hf alloys.	338
7.16	Comparison of MIK-T and measured values of GB Cr depletion for the +Zr and +Hf alloys irradiated at 400°C to 3 dpa.	339
7.17	Comparison of MIK-T and measured values of GB Cr depletion for the +Zr and +Hf alloys irradiated at 400°C to 7 dpa.	340
7.18	Comparison of MIK-T and measured values of GB Cr depletion for the +Zr and +Hf alloys irradiated at 500°C to 1 dpa.	341
7.19	Comparison of MIK-T and measured values of GB Cr depletion for the +Zr and +Hf alloys irradiated at 500°C to 3 dpa.	342
7.20	Binding energy as a function of nearest neighbor distance from the oversized solute. The top x-axis also includes the distance from the origin (oversized solute atom position), in nm.	343
7.21	Amount of GB Cr depletion at $400^{\circ}$ C for LoZr and HiZr at 7 dpa compared to the MIK-T model using a binding energy of $0-0.3$ eV.	344
7.22	Amount of GB Cr depletion as a function of binding energy at 400°C for LoHf and HiHf at 10 dpa compared to the MIK-T model	345
7.23	Amount of GB Cr depletion as a function of solute concentration in solution for LoZr and HiZr at 400°C, 7 dpa. Trapping and recombination radii are 0.5 nm, and binding energies are 1.08 eV for Zr and 0.71 eV for Hf	346
7.24	Amount of GB Cr depletion as a function of solute concentration in solution for LoHf and HiHf at 400°C, 10 dpa. Trapping and recombination radii are 0.5 nm, and binding energies are 1.08 eV for Zr and 0.71 eV for Hf	347
7.25	Drawing of the concentration of solute in a unit cell as a function of the radius of the unit cell, where $r = \alpha$ at the precipitate boundary and $r = r_e$ at the unit cell boundary, $c_0$ is the initial solute concentration in the unit cell,	

	$\bar{c}$ is the average solute concentration as a function of irradiation time, and $c'$ is the equilibrium solute concentration at the precipitate boundary	348
	is the equinorium solute concentration at the precipitate boundary	340
7.26	Hf concentrations remaining in the matrix as a function of irradiation dose at temperatures of 400°C and 500°C, based on the Cr vacancy diffusion	
	coefficient, using a precipitation kinetics analysis developed by Shewmon	349
7.27	Hf concentration remaining in the matrix as a function of density at	
	temperatures of 400°C and 500°C, based on the Cr vacancy diffusion	
	coefficient, using a precipitation kinetics analysis developed by Shewmon. The vertical line shows the reference value for the migration energy of 1.18	
	eV	350
7 20	Communican of MIV. T model and management values of CD. Cr. depletion at	
1.28	Comparison of MIK-T model and measured values of GB Cr depletion at 400°C for HiHZr and HiHf. Oversized solute concentrations for the MIK-T	
	model are the estimated values prior to irradiation based on TEM imaging of	
	ZrC and HfC precipitate microstructure, with 0.11 at% Zr for HiZr and 0.16 at% Hf for HiHf	351
	at/6 HI 101 HIHI	331
7.29	Correlation of Cr depletion measurements and LEAP analysis, where for	
	each irradiation condition, the detection of oversized solute in solution is consistent with the measured reduction of Cr depletion.	352
	consistent with the measured reduction of Cr depiction	332
7.30	Grain boundary Cr depletion as a function of oversized solute concentration	2.52
	for LoZr and HiHf at 400°C, 3 dpa	353
B.1	(a) Selection of an area for Pt deposition to protect the sample during	
	cutting; (b) after deposition of Pt; (c) arrangement of a series of box cuts to drill out a sample post; (d) after the first set of box cuts performed at +52°;	
	(e) a second box cutting at -10° undercuts the sample, leaving a cantilevered	
	sample post; (f) a full view of the post under a protective Pt layer, with	
	surrounding ion beam drilling damage.	374
B.2	(a) The Kleindiek tungsten probe is maneuvered and placed on top of the	
	sample post; (b) a top-down view reveals a shadow on the post from the	
	probe; (c) deposition of Pt connects the post to the probe; (d) a final cut releases the sample from the TEM foil; (e) and the probe plus sample post	
	are removed and positioned for the next step in the fabrication process	375
B.3	(a) The sample attached to a tungsten wire is reloaded back into the FIB and	
<b>D</b> .5	imaged in the e beam; (b) box mill of the post edge, with imaging in the	
	Ga <sup>+</sup> beam; (c) large annular milling pattern to establish the initial shape of	
	the sample tip; (d) final annular milling pattern to shape and define the final sample tip; and (e) an image of the final specimen tip.	376
	builded up, and (o) an image of the imal specificitup,	

B.4	(a) an image of a primary and secondary tip after the final milling process,	
	imaged in the e beam; (b) close up view of the primary peak; (c) image of a	
	primary tip without any secondary tips that might interfere with LEAP	
	analysis; and (d) a close of the final specimen tip showing the final tip	
	diameter of less than 100 nm.	377
C.1	EDS spectrum for a grain boundary RIS measurement showing the $K_{\beta 1}^{Ni}$ X-	
	ray peak and the position of the $L_{\alpha 1}^{Hf} + L_{\alpha 2}^{Hf}$ X-ray peak	380

### LIST OF TABLES

<u>Table</u>		
2.1	Segregation predictions based on volume misfit of solute in a binary alloy	51
2.2	Estimated binding energies for oversized solutes in a 316L stainless steel	52
2.3	RIS data for a series of 316SS with Pt or Hf additions, irradiated with protons at 400°C to doses of 2.5 and 5 dpa	53
2.4	Grain boundary concentration data for a FeCrNi alloy with Zr additions after neutron irradiation	54
2.5	A 316+Zr alloy after 1 MeV electron irradiation to doses of 0.85 and 3.4 dpa with, (a) the average void diameter, and (b) the void density, as a function of temperature	55
2.6	Experimentally-determine linear size factors of oversized solute atoms in a Fe-Cr-Ni alloy	56
4.1	Summary of bulk alloy compositions (wt%) determined by chemical analysis	124
4.2	Thermo-mechanical heat treatments and processing steps taken to achieve an average grain size of approximately 20 µm for each alloy	125
4.3	X-ray emission energies for elements analyzed in composition analysis, including the energy window used for each window in the Emispec ES Vision software	126
4.4	Rules for calculating the propagation of error for <i>Z</i> based on two quantities, <i>A</i> and <i>B</i> , each of which have an associated error	127
5.1	Grain boundary (GB) measurements of concentration for the +Zr alloys irradiated with protons at 400°C to doses of 3, 7 and 10 dpa	173

5.2(a	Grain boundary segregation and measurement error for the +Zr alloys irradiated with protons at 400°C to doses of 3, 7 and 10 dpa	174
5.2(b	b) Error in the segregation measurements calculated using error propagation from the standard deviations (σ) of the grain boundary and matrix measurements for the +Zr alloys at 400°C to doses of 3, 7 and 10 dpa	174
5.3	Grain boundary measurements of concentration for the +Zr alloys irradiated with protons at 400°C to doses of 3, 7 and 10 dpa, normalized to Fe + Cr + $Ni = 1$	175
5.4	Grain boundary (GB) measurements of concentration for the +Hf alloys irradiated with protons at 400°C to doses of 3, 7 and 10 dpa	176
5.5(a	Grain boundary segregation for the +Hf alloys irradiated with protons at 400°C to doses of 3, 7 and 10 dpa	177
5.5(b	b) Error in the segregation measurements calculated using error propagation from the standard deviations (σ) of the grain boundary and matrix measurements for the +Hf alloys at 400°C to doses of 3, 7 and 10 dpa	177
5.6	Grain boundary measurements of concentration for the +Hf alloys irradiated with protons at $400^{\circ}\text{C}$ to doses of 3, 7 and 10 dpa, normalized to Fe + Cr + Ni = 1	178
5.7	Grain boundary (GB) measurements of concentration for the +Zr alloys irradiated with protons at 500°C to doses of 1 and 3 dpa	179
5.8(a	a) Grain boundary segregation for the +Zr alloys irradiated with protons at 500°C to doses of 1 and 3 dpa	180
5.8(b	b) Error in the segregation measurements calculated using error propagation from the standard deviations (σ) of the grain boundary and matrix measurements for the +Zr alloys at 500°C to doses of 1 and 3 dpa	180
5.9	Grain boundary measurements of concentration for the +Zr alloys irradiated with protons at 500°C to doses of 1 and 3 dpa, normalized to Fe + Cr + Ni = 1	181
5.10	Grain boundary (GB) measurements of concentration for the +Hf alloys irradiated with protons at 500°C to doses of 1 and 3 dpa	182
5.11(	(a) Grain boundary segregation for the +Hf alloys irradiated with protons at 500°C to doses of 1 and 3 dpa	183

5.11(	(b) Error in the segregation measurements calculated using error propagation from the standard deviations (σ) of the grain boundary and matrix measurements for the +Zr alloys at 500°C to doses of 1 and 3 dpa	183
5.12	Grain boundary measurements of concentration for the +Hf alloys irradiated with protons at 500°C to doses of 1 and 3 dpa, normalized to Fe + Cr + Ni = 1	184
5.13	Measured dislocation loop data for the +Zr alloys after 400°C irradiation at doses of 3 and 7 dpa	185
5.14	Measured dislocation loop data for the +Hf alloys after 400°C irradiation at doses of 3 and 7 dpa. Loop density error represents the standard deviation of the loop density measurements.	186
5.15	IDCC data for ZrC and HfC including 20 diffraction angles, inter-planar distance (d), relative intensities, and (hkl) planes	187
5.16	XRD results of the bulk lattice parameter and phases detected for the oversized solute alloys and the reference alloys, along with an estimated mass fraction of the secondary XC phases present in the oversized solute alloys	188
5.17	Experimental lattice parameters for carbide phases	189
5.18	Mean size and density of HfC and ZrC precipitates (ppts.) in HiHf and HiZr, respectively, with the amount of Hf/Zr in the precipitates and remaining in solution.	190
5.19	$\mathrm{Ni}^{2^{+}}$ mass/charge ratios with isotopic abundances. The $\mathrm{Ni}^{2^{+}}$ ratios overlap with the $\mathrm{Zr}^{3^{+}}$ .	191
5.20	$\mathrm{Mo}^{2+}$ mass/charge ratios with isotopic abundances. Some of the $\mathrm{Mo}^{2+}$ ratios overlap with $\mathrm{Zr}^{2+}$ ratios.	192
5.21	Zr <sup>2+</sup> and Zr <sup>3+</sup> mass/charge ratios with isotopic abundances. Mass/charge ratios for both Mo and Ni overlap with Zr, making identification of Zr difficult	193
5.22	The Hf <sup>2+</sup> and Hf <sup>3+</sup> mass/charge ratios with isotopic abundances. High mass/charge ratios for Hf make detection more difficult at low concentrations.	194
5.23	Results from the identification of oversized solute in LEAP sample analysis	195
6.1	MIK model input values	260

6.2	Standard values of the MIK-T model input parameters used for the sensitivity study	261
6.3	Changes in grain boundary concentration and the significance of MIK-T model input parameters at 400°C and 1 dpa after changing the input values by a factor of 10 <sup>-4</sup>	262
6.4	Changes in grain boundary concentration and the significance of MIK-T model input parameters at 500°C and 1 dpa after changing the input values by a factor of 10 <sup>-4</sup>	263
6.5	Binding energy as a function of nearest neighbor distance for Zr or Hf in non-spin-polarized Fe using the indirect method.	264
6.6	Binding energy as a function of nearest neighbor distance using the direct method, first for Zr or Hf in non-polarized Fe with an additional <i>p</i> -shell of electrons, and also Zr in spin-polarized Fe	265
6.7	Calculated lattice parameters and linear size factors for Zr and Hf in fcc Fe plus experimental size factors	266
<b>A</b> .1	Production of relevant isotopes in the (p <sup>+</sup> ,n) reaction	363
A.2	Irradiation parameters in calculating activity	364
A.3	Production of radioactivity through the (p <sup>+</sup> ,n) reaction after 3 dpa	365
A.4	Post-irradiation radioactivity for 2, 3, and 3.2 MeV protons after 3 dpa	366
A.5	Summary of sample activity after 2, 3, and 3.2 MeV proton irradiation	367

### LIST OF APPENDICES

# <u>Appendix</u>

A.	ACTIVITY CALCULATIONS	359
B.	LEAP SAMPLE FABRICATION	368
C.	MINIMUM DETECTABILITY LIMIT OF HF IN EDS	378
D	RADIATION-INDUCED SEGREGATION MEASUREMENTS	381